

## Low voltage high performance NPN power transistor

### Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

### Applications

- Emergency lighting
- LED drive
- Motherboard and hard disk drive
- Mobile equipment
- DC-DC converter, voltage regulation

### Description

The device is a NPN transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

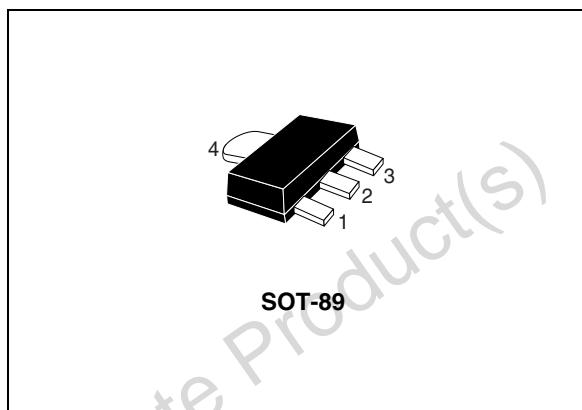


Figure 1. Internal schematic diagram

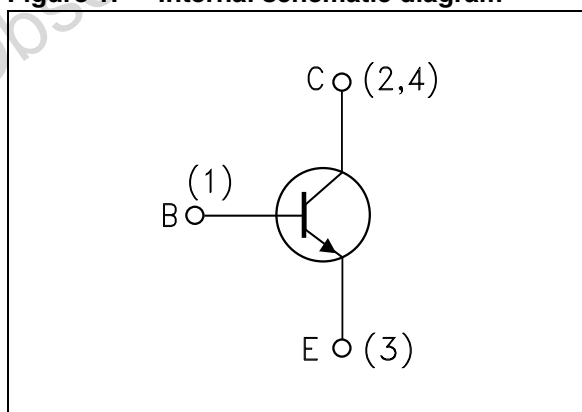


Table 1. Device summary

Order codes	Marking	Package	Packaging
2STF1525	1525	SOT-89	Tape and reel

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CEX}$	Collector-emitter voltage ( $V_{BE} = -1.5\text{ V}$ )	95	V
$V_{CEO}$	Collector-emitter voltage ( $I_B = 0$ )	25	V
$V_{EBO}$	Emitter-base voltage ( $I_C = 0$ )	5	V
$I_C$	Collector current	5	A
$I_{CM}$	Collector peak current ( $t_P < 5\text{ ms}$ )	10	A
$I_B$	Base current	1	A
$P_{TOT}$	Total dissipation at $T_{amb} = 25\text{ °C}$	1.4	W
$T_{STG}$	Storage temperature	-65 to 150	°C
$T_J$	Max. operating junction temperature	150	°C

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJA}^{(1)}$	Thermal resistance junction-ambient max	89	°C/W

1. Device mounted on PCB area of  $1\text{ cm}^2$

## 2 Electrical characteristics

$T_{\text{case}} = 25\text{ °C}$  unless otherwise specified.

**Table 4. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CBO}}$	Collector cut-off current ( $I_{\text{E}} = 0$ )	$V_{\text{CB}} = 50\text{ V}$			0.1	$\mu\text{A}$
$I_{\text{EBO}}$	Emitter cut-off current ( $I_{\text{C}} = 0$ )	$V_{\text{EB}} = 4\text{ V}$			0.1	$\mu\text{A}$
$V_{(\text{BR})\text{CEX}}$	Collector-emitter breakdown voltage ( $V_{\text{BE}} = -1.5\text{ V}$ )	$I_{\text{C}} = 1\text{ mA}$	95			V
$V_{(\text{BR})\text{CEO}}^{(1)}$	Collector-emitter breakdown voltage ( $I_{\text{B}} = 0$ )	$I_{\text{C}} = 10\text{ mA}$	25			V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ( $I_{\text{C}} = 0$ )	$I_{\text{E}} = 100\text{ }\mu\text{A}$	5			V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 0.5\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ $I_{\text{C}} = 3\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ $I_{\text{C}} = 5\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	150 100	150	500	
$V_{\text{CE}(\text{sat})}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 3\text{ A}$ $I_{\text{B}} = 300\text{ mA}$ $I_{\text{C}} = 3.5\text{ A}$ $I_{\text{B}} = 40\text{ mA}$		220	500	mV mV
$V_{\text{BE}(\text{sat})}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 3\text{ A}$ $I_{\text{B}} = 300\text{ mA}$			1.2	V
$C_{\text{CBO}}$	Collector-base capacitance ( $I_{\text{E}} = 0$ )	$V_{\text{CB}} = 10\text{ V}$ , $f = 1\text{ MHz}$		20		pF
$f_{\text{T}}$	Transition frequency	$V_{\text{CE}} = 10\text{ V}$ $I_{\text{C}} = 50\text{ mA}$		120		MHz
$t_{\text{on}}$	Resistive load Turn-on time	$I_{\text{C}} = 1.5\text{ A}$ $V_{\text{CC}} = 10\text{ V}$		60		ns
$t_{\text{off}}$	Turn-off time	$I_{\text{B}1} = -I_{\text{B}2} = 150\text{ mA}$		450		ns

1. Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$

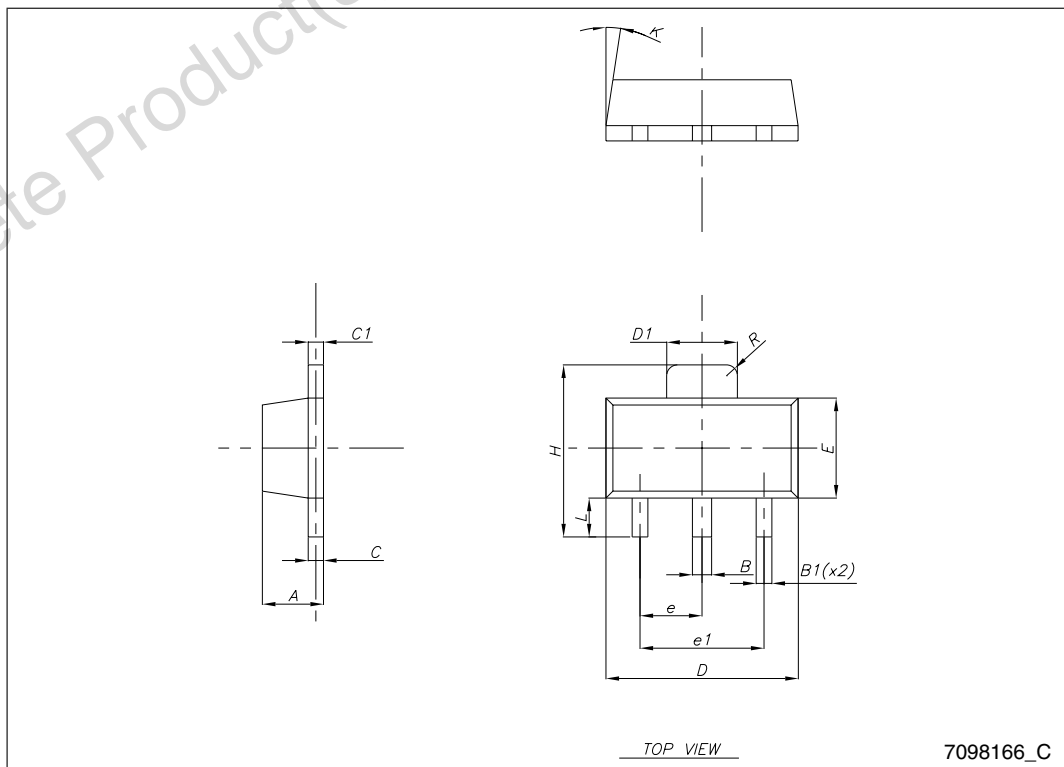
### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

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**SOT-89 mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	1.40		1.60
B	0.44		0.56
B1	0.36		0.48
C	0.35		0.44
C1	0.35		0.44
D	4.40		4.60
D1	1.62		1.83
E	2.29		2.60
e	1.42		1.57
e1	2.92		3.07
H	3.94		4.25
K	1°		8°
L	0.89		1.20
R		0.25	



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## 4 Revision history

**Table 5. Document revision history**

Date	Revision	Changes
04-Jun-2009	1	Initial release.
12-Nov-2009	2	Document status promoted from preliminary data to datasheet.

Obsolete Product(s) - Obsolete Product(s)

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